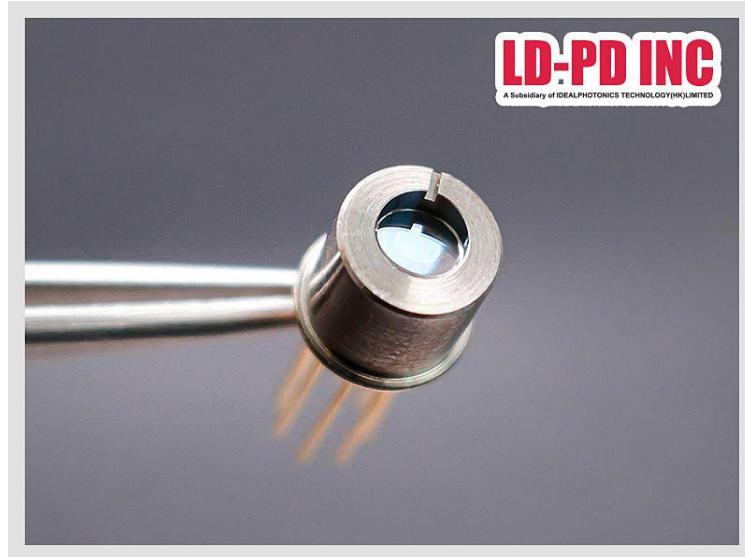


## 1297nm DFB Laser diode for HF Sensing (TO39 Package)



### Description

The PL-DFB-1297-A-A81-TO39 1297nm DFB laser diode module made by LD-PD is a cost effective, highly coherent laser source. The DFB laser diode chip is packaged in an industry standard hermetically sealed TO39 package with TEC and PD Built in.

### Features

- Narrow Linewidth < 2MHz
- Excellent wavelength control and stability
- Industry Standard 14 pin Butterfly package
- Mode-Hop free tuning
- Excellent reliability
- Customer specific wavelengths available

### Application

- Tunable diode laser absorption spectroscopy
- HF Monitoring

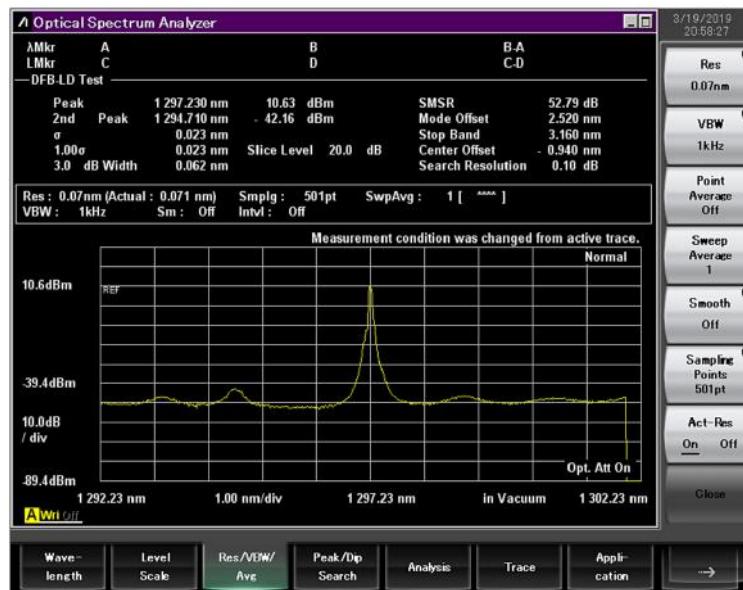
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## Laser Specifications

Electrical/Optical Characteristics(T<sub>sub</sub>=25°C, CW bias unless stated otherwise)

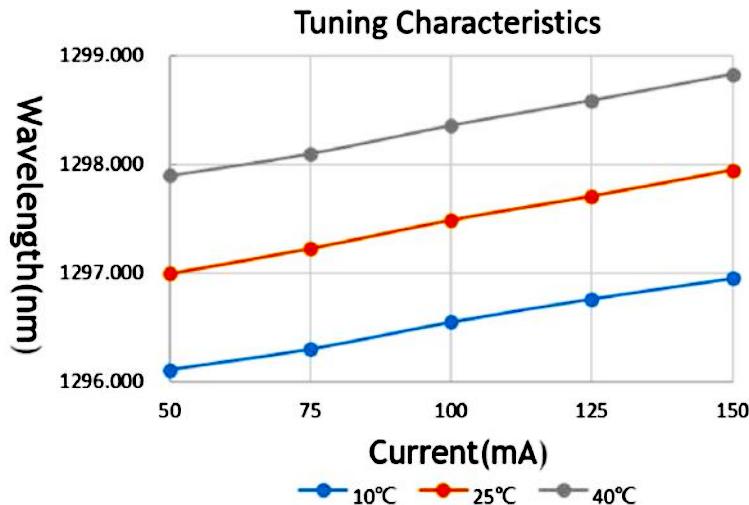
Parameter	Symbol	Min	Typ	Max	Unit
Centre Wavelength	$\lambda$	1296.5	1297.0	1297.5	nm
Side Mode Suppression Ratio	SMSR	30	40		dB
Threshold Current	I <sub>th</sub>		20	30	mA
Operating Current	I <sub>op</sub>		80	120	mA
Chip output Power	P <sub>f</sub>	10	15	30	mW
Quantum Efficiency	$\eta$	0.08	0.12		mW/mA
Current Tuning Coefficient	$\Delta\lambda/\Delta I$		0.015		nm/mA
Temperature Tuning Coefficient	$\Delta\lambda/\Delta T$		0.12		nm/K
Forward Voltage	V <sub>f</sub>		1.3	2	V
Thermistor Resistance	R <sub>T</sub>	9.5	10	10.5	KΩ
Thermistor Temp. Coefficient			-4.4		%/°C
Connector	FC/APC				

## Spectrum

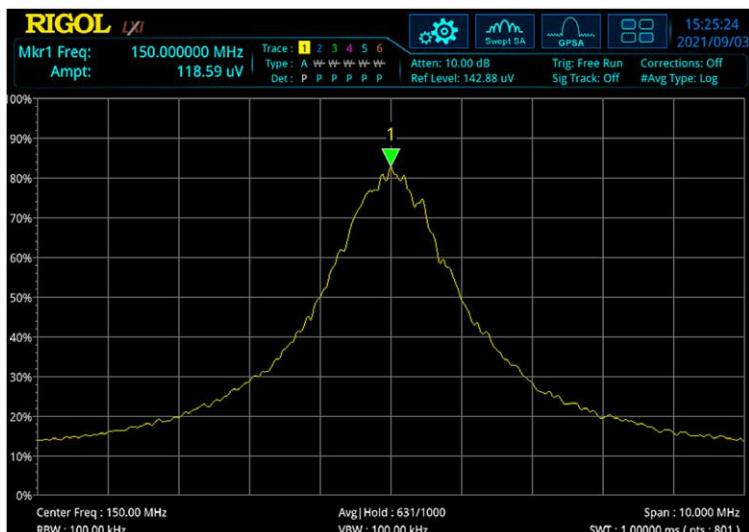


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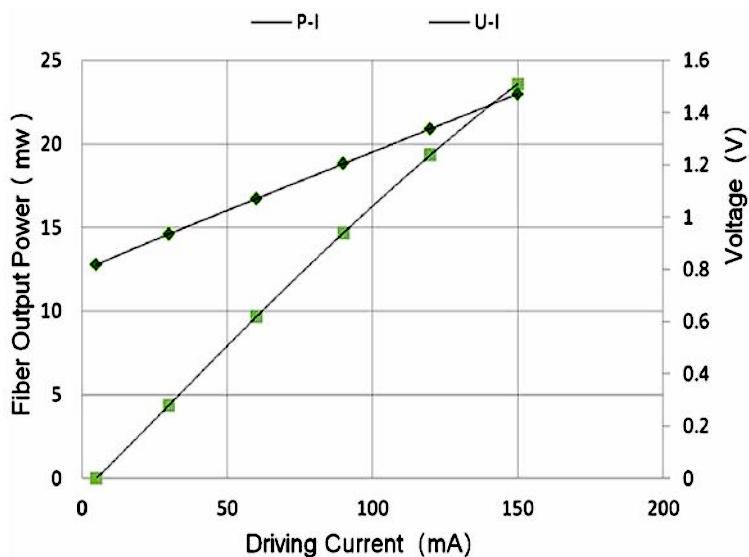
## Tuning Characteristics



## DFB Linewidth Testing Result

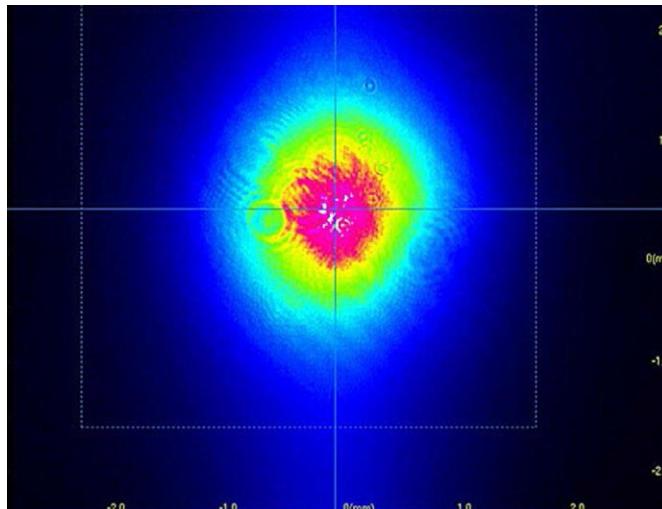


## L-I Curve

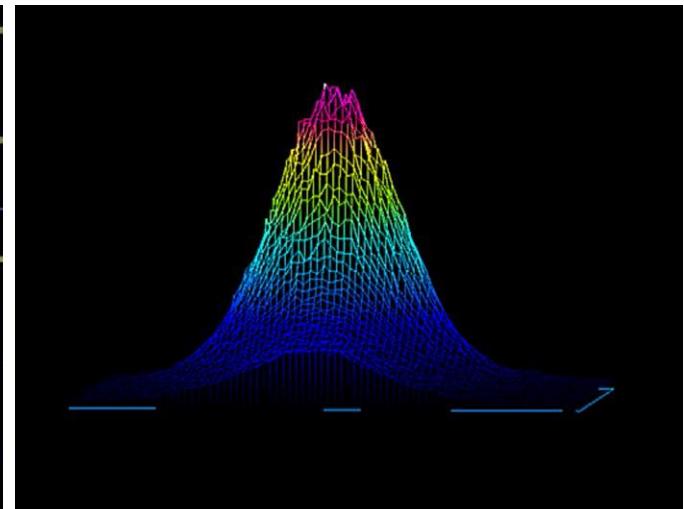


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## Beam Quality

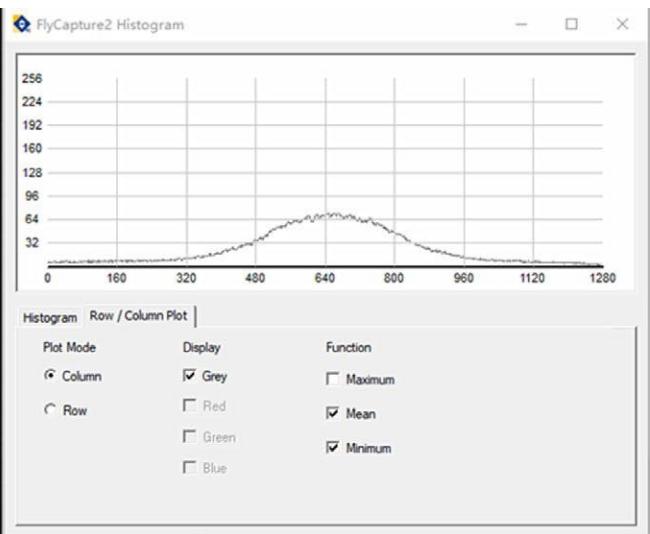
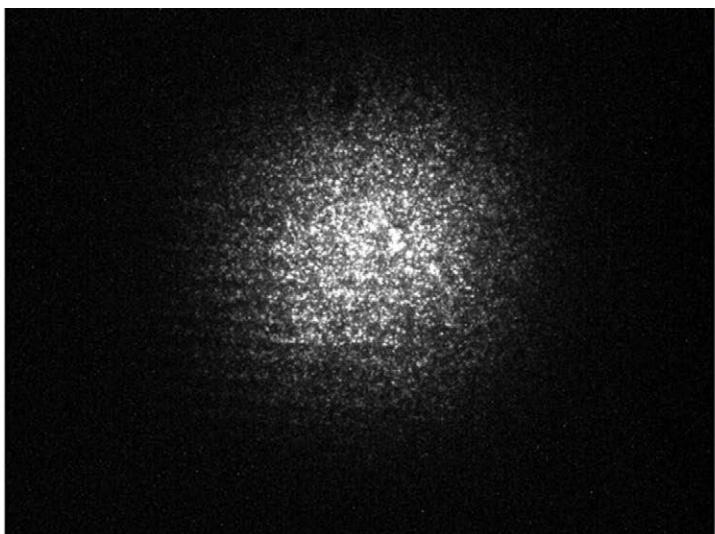


2D



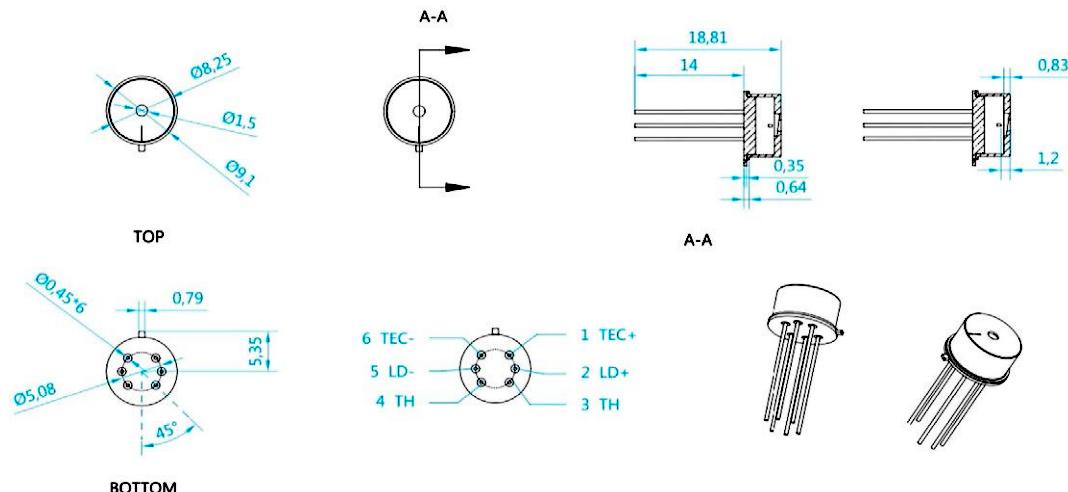
3D

## Camera Analysis



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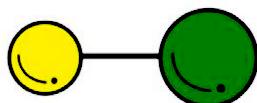
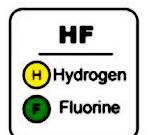
## Dimensions and Pin definitions



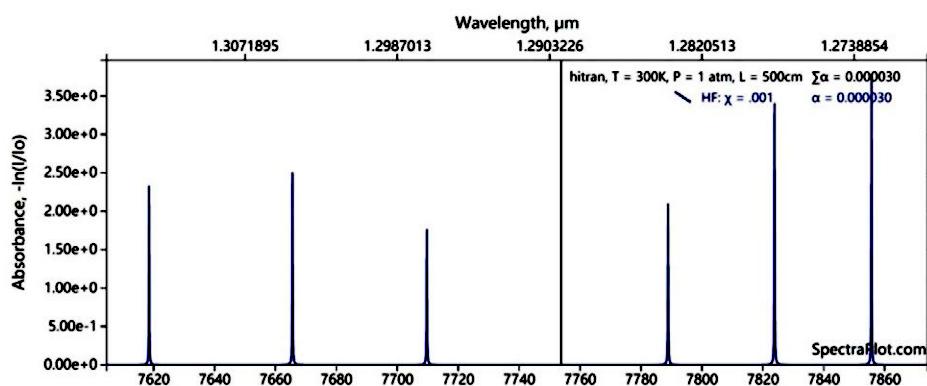
## Absolute Maximum Ratings

Item	Unit	Min	Typ	Max
Case Temperature	°C	-5	25	70
Chip Temperature	°C	+10	25	40
Operating Current	mA	0	100	120
Forward Voltage	V	0.8	1.2	1.8
TEC Current	A	-	-	1.2
Reverse Voltage (LD)	V	-	-	2.0
Reverse Voltage (PD)	V	-	-	20

## HF



TDLAS: 1278/1297/1312nm



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## Ordering Info

**PL-DFB-□□□□-☆-A8▽-TO39**

□□□□:Wavelength

1297: 1297nm

\*\*\*\*\*

1653.7: 1653.7nm

☆ :Output Power

A:15mW

B:30mW

▽:Wavelength Tolerance

1: $\pm 1$ nm

2: $\pm 2$ nm

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